# NSN 5962-01-344-0978

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View Online at https://aerobasegroup.com/nsn/5962-01-344-0978

Overall Length:
1.485 inches
Overall Height:
Between 0.245 inches and 0.430 inches
Body Length:
1.485 inches
Body Width:
Between 0.240 inches and 0.310 inches
Body Height:
Between 0.130 inches and 0.215 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Parallel operation and monolithic and w/reset
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
15 input
Case Outline Source And Designator:
D-15 mil-m-38510
Current Rating Per Characteristic:
50.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable
Terminal Surface Treatment:
Gold
Product Name:
Parallel fifo
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
30.00 nanoseconds access
Memory Device Type:
First-in first-out
Precious Material And Location:
Terminal surfaces gold

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**Precious Material:** 

Gold

## **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## **Terminal Type And Quantity:**

28 printed circuit

## Shelf Life:

N/a

## Unit Of Measure:

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### Demilitarization:

Yes - demil/mli

#### Fiig:

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